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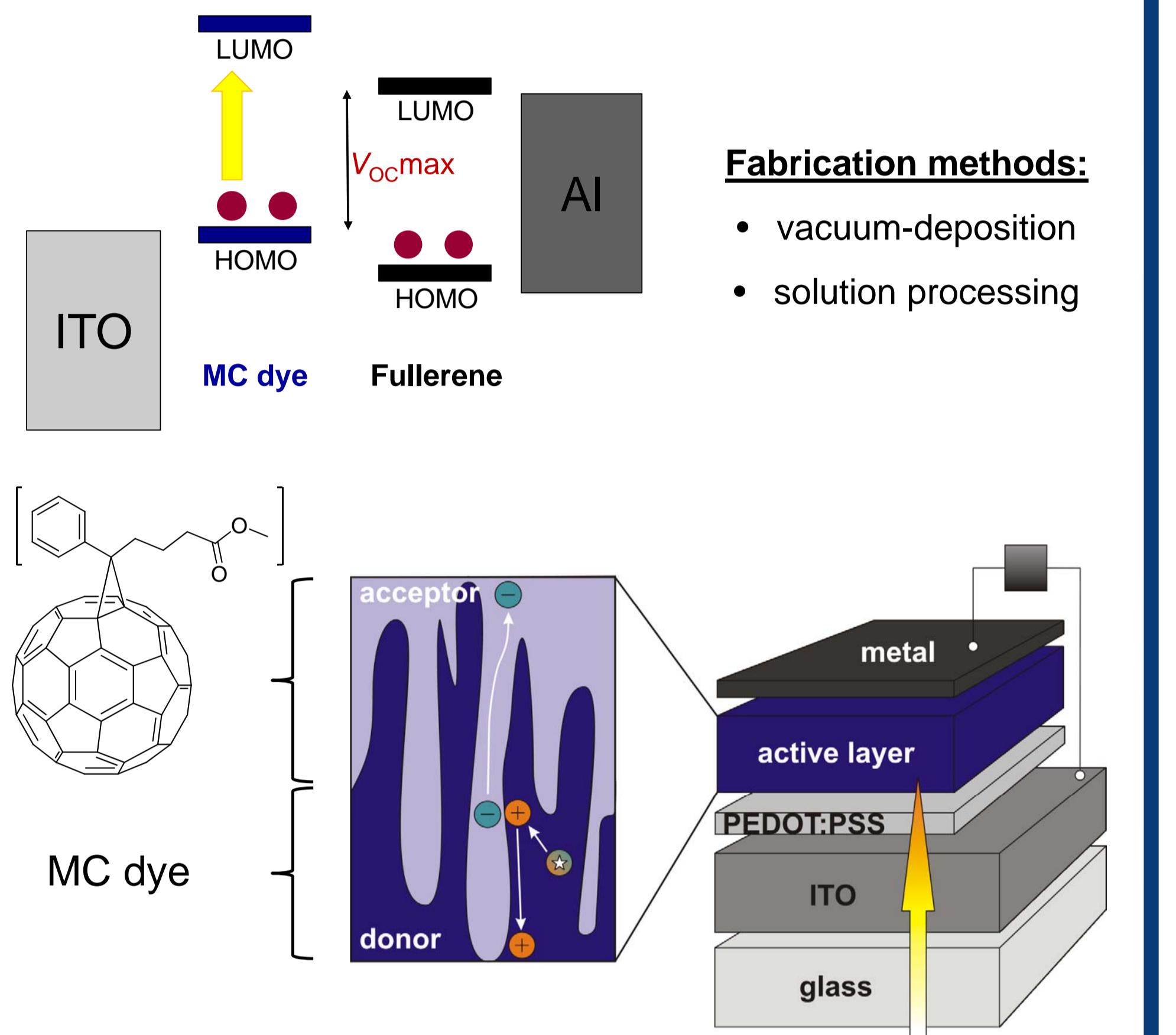
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Introduction

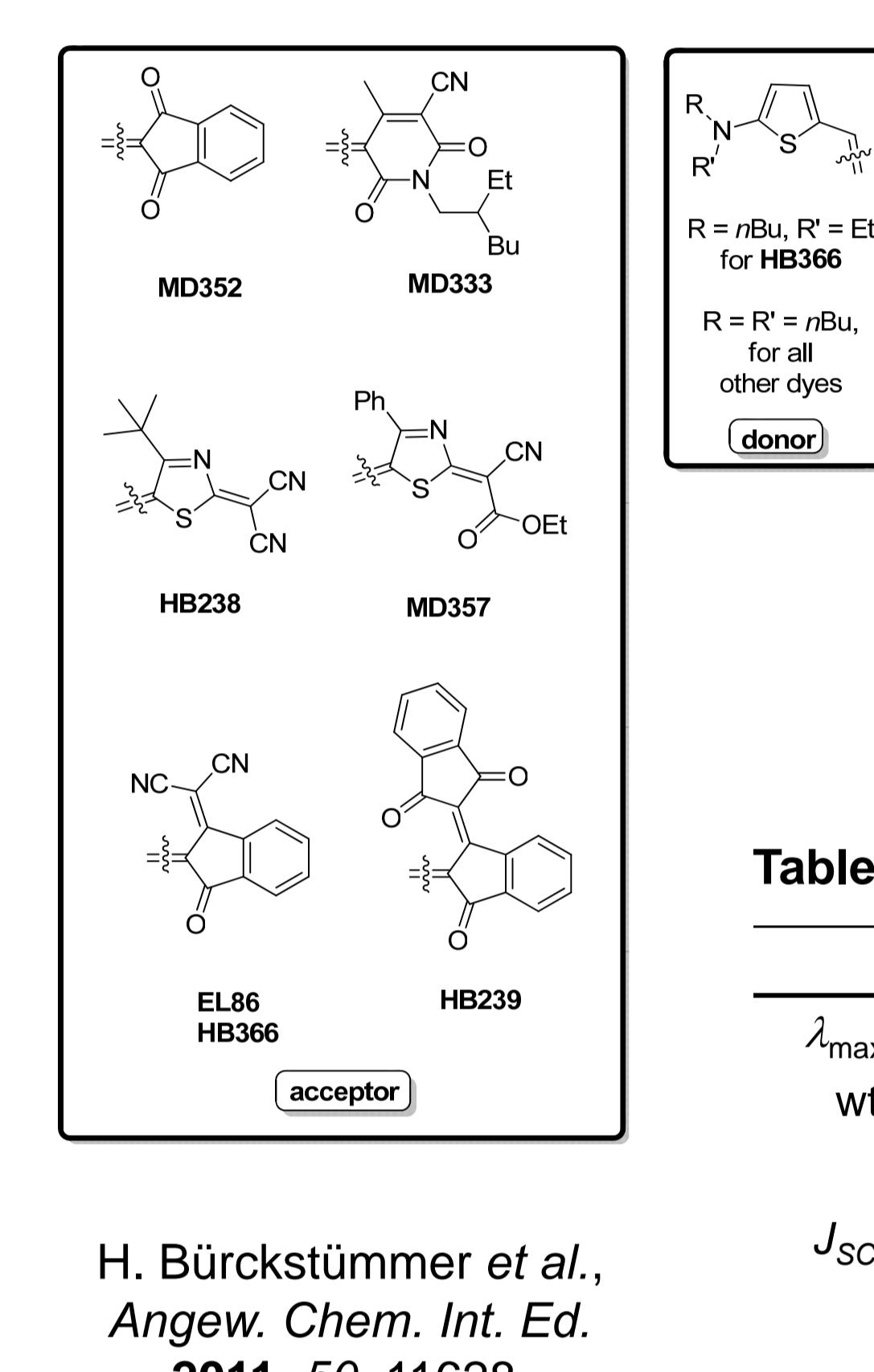
Photovoltaic devices based on organic compounds bear the potential for large-scale and cost-effective power generation. Especially, the investigation of organic small molecules electronic materials for organic photovoltaics and thin-film transistors (OTFTs) has attracted considerable interest due to the simple purification procedures of the compounds.

During the last years, we have developed a series of merocyanine (MC) dyes which showed power conversion efficiencies (η) of up to 6.1 % in BHJ solar cells combined with fullerene acceptor materials.^[1] Furthermore, we have investigated OTFTs with MC compounds as p-type semiconductors, and reported the first high-performance OTFT based on a highly dipolar donor-acceptor (D-A) molecule.^[2]

MC dye based BHJ solar cells



Variation of the acceptor unit



H. Bürckstümmer et al.,
Angew. Chem. Int. Ed.
2011, 50, 11628.

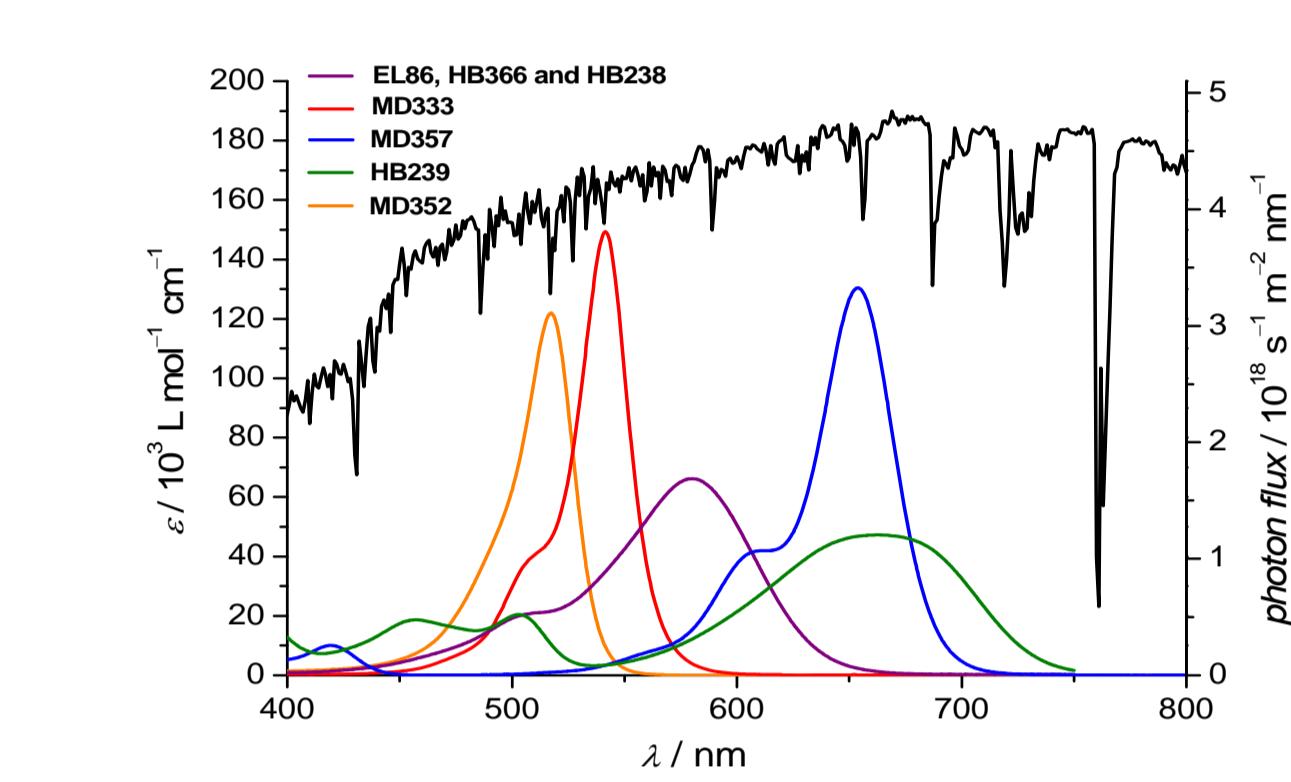


Figure 1. UV/Vis spectra of MC dyes in CH_2Cl_2 and solar photon flux at AM 1.5 conditions (black).

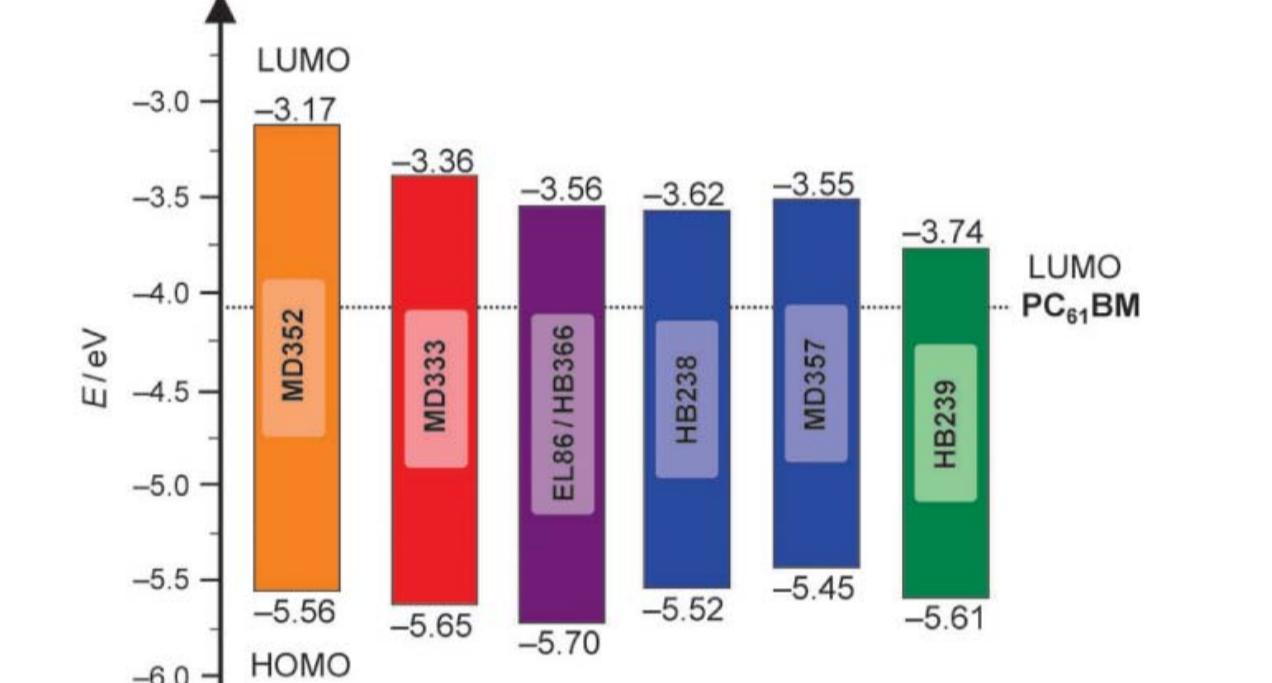


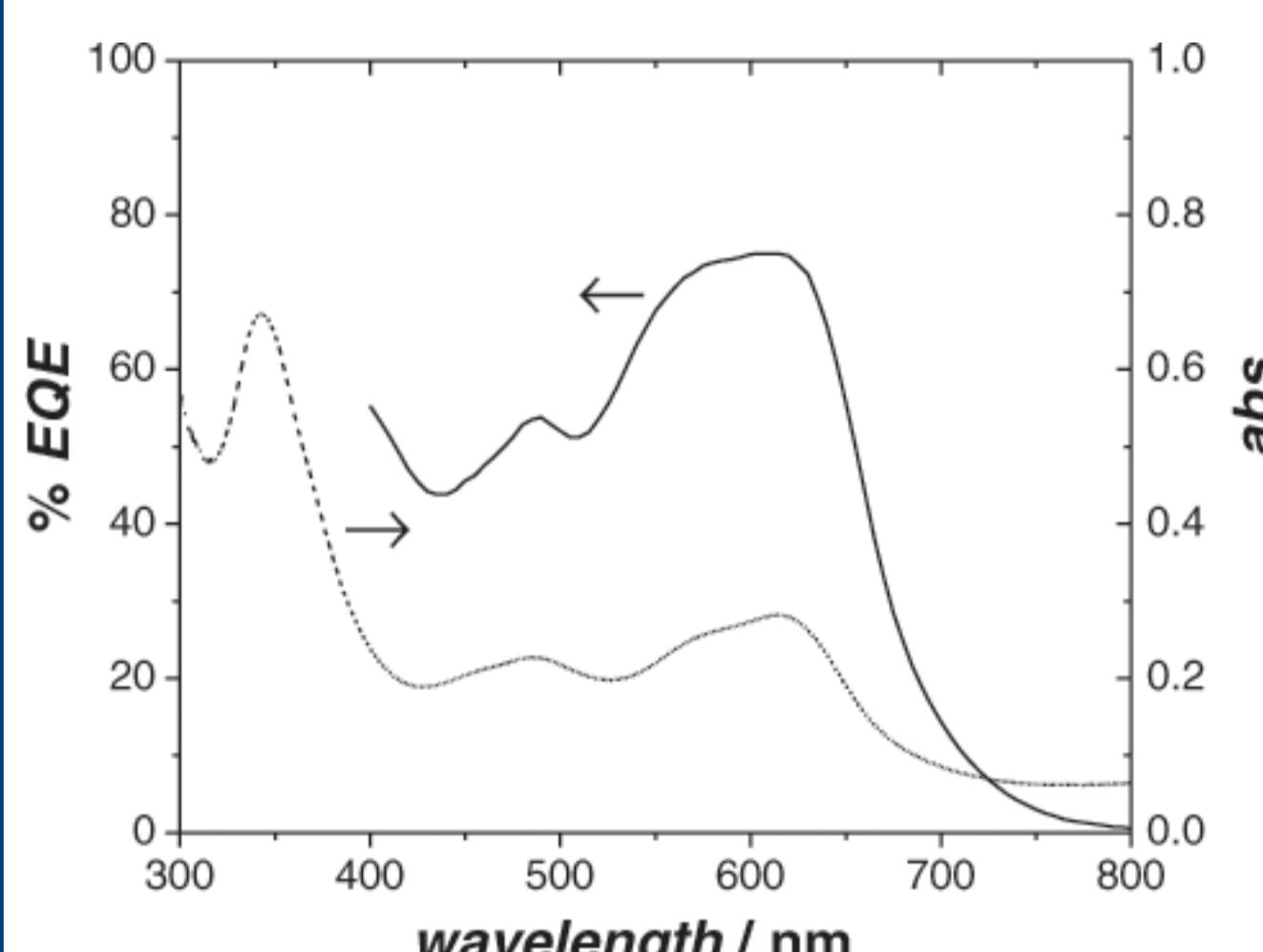
Figure 2. FMO levels, band gaps of dyes and their relative position to the LUMO of PC_{61}BM .

Table 1. Cell characteristics of chlorobenzene solution-cast solar cells.

	MD352	MD333	EL86	HB366	HB238	MD357	HB239
λ_{max} (film) / nm	532	556	595	595	682	689	700
wt% PCBM	70	70	60	55	75	70	75
V_{oc} / V	0.63	0.73	0.96	0.94	0.72	0.47	0.68
J_{sc} / mA cm ⁻²	2.9	4.0	5.8	8.3	4.5	4.0	4.0
FF	0.27	0.32	0.41	0.38	0.35	0.27	0.36
η / %	0.5	0.9	2.3	3.0	1.1	0.5	1.0

Best performance

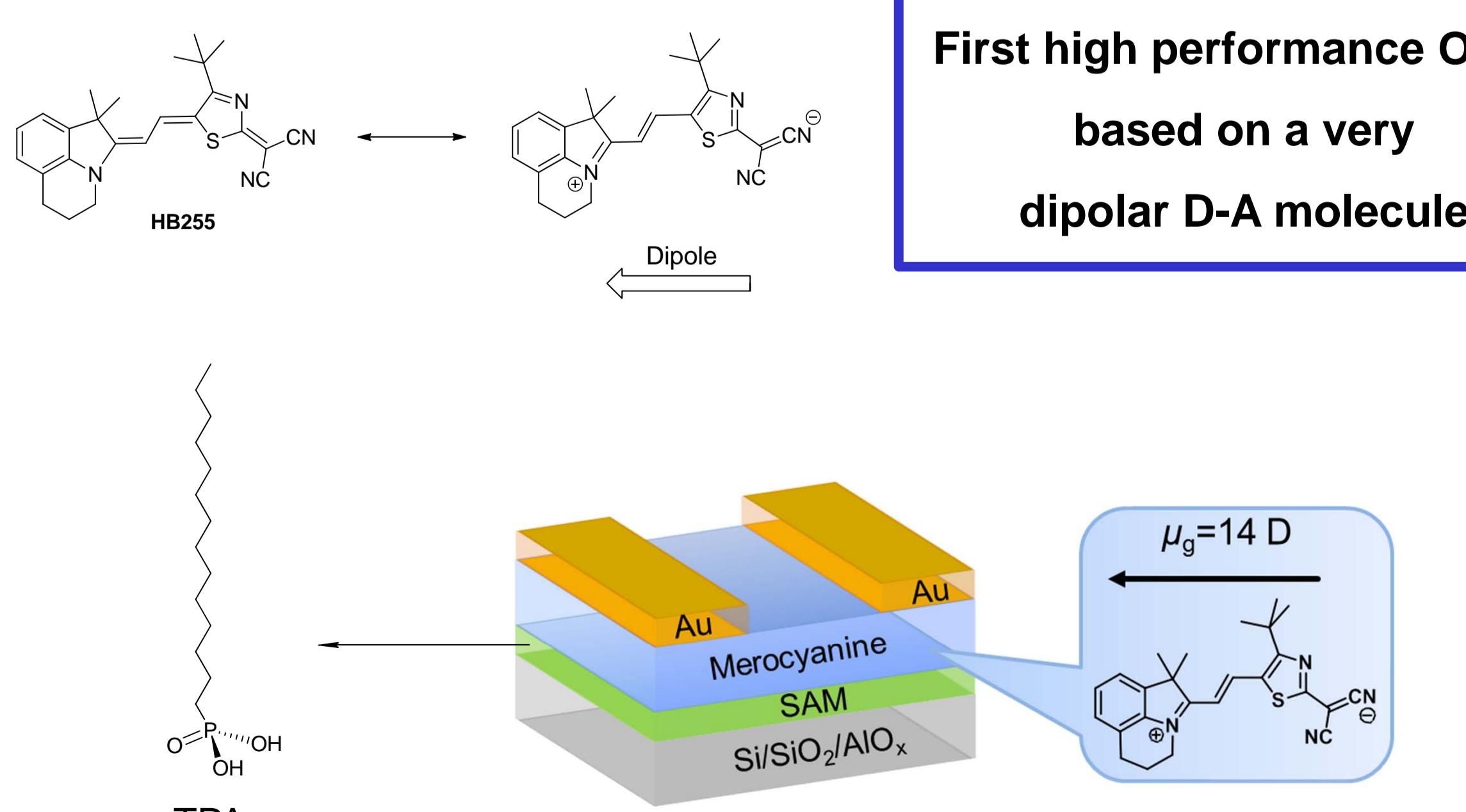
Vacuum-processed BHJ solar cell:



- active layer (55 nm): HB194 : C_{60} = 9 : 11
 - exciton blocking layer (6 nm): Bphen
 - hole-collecting contact layer (20 nm): MoO_3
- Solar cell characteristics**
- | | |
|-------------------------------------|-------------------|
| J_{sc} = 12.6 mA cm ⁻² | V_{oc} = 0.96 V |
| FF = 0.47 | η = 6.1% |

V. Steinmann et al., *Adv. Energy Mater.* 2011, 1, 888.

High-Performance OTFT



L. Huang et al., *Adv. Mater.* 2012, 24, 5750.

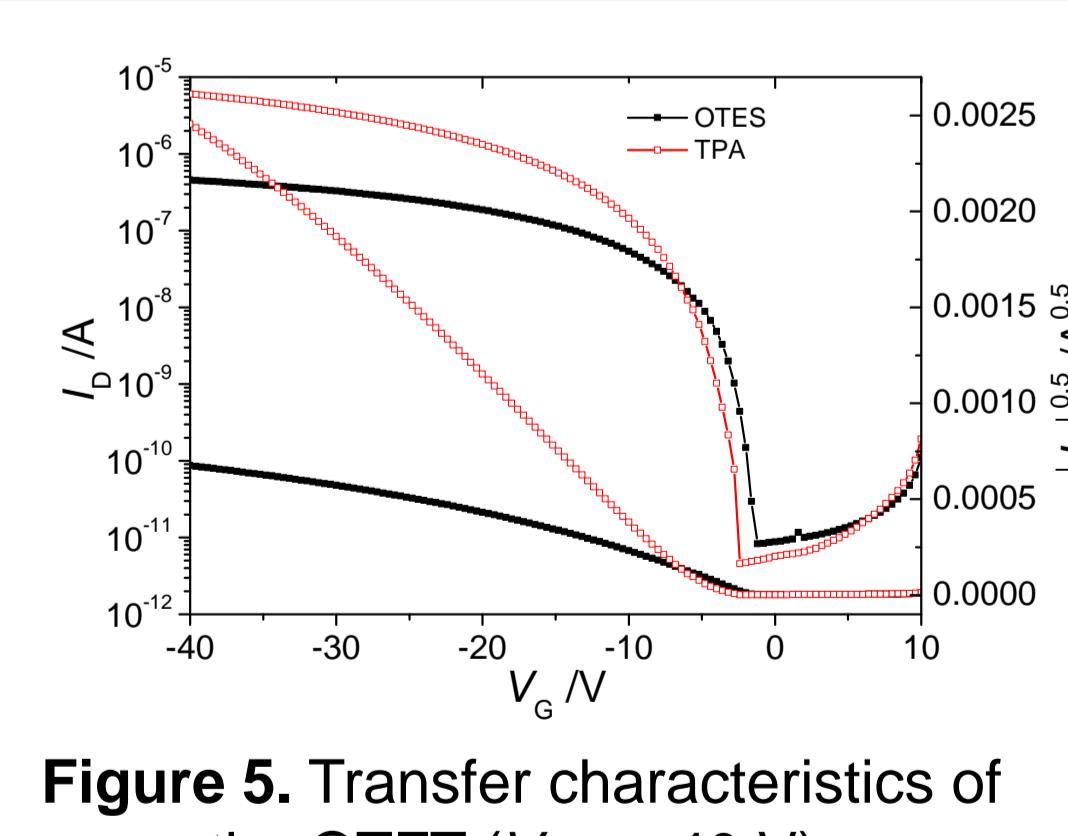


Figure 5. Transfer characteristics of the OTFT (V_D = -40 V).

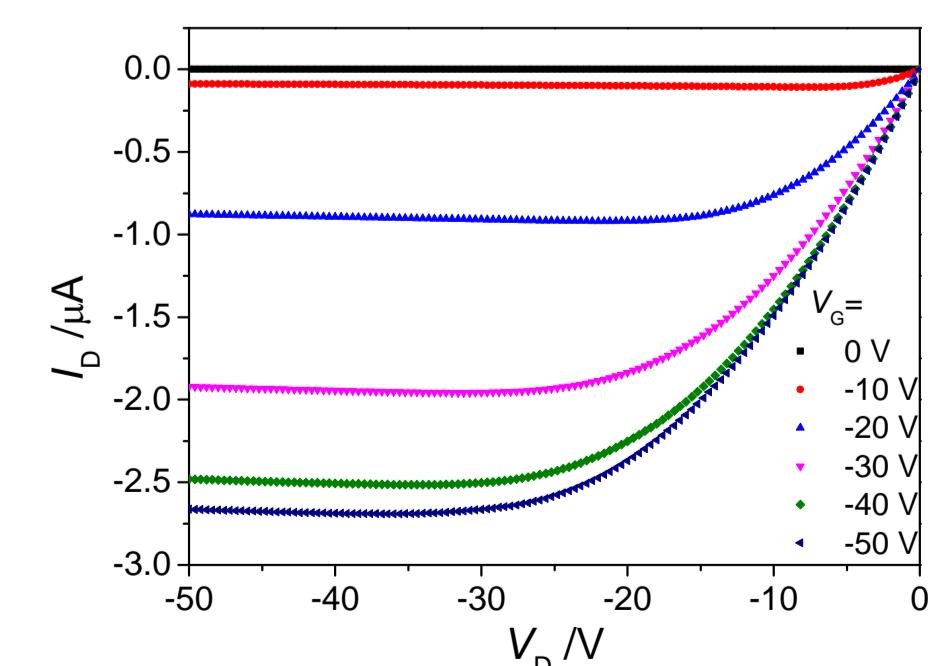


Figure 6. Output characteristics of the OTFT on TPA substrate.

Table 2. Transistor characteristics.

T_s / °C	μ / cm ² V ⁻¹ s ⁻¹	V_T / V	I_{on}/I_{off}
80	0.08 - 0.09	-5 ± 1	10 ⁶
100	0.16 - 0.17	-5 ± 1	10 ⁵
120	0.17 - 0.18	-5 ± 1	10 ⁶

Ordered crystalline films
and antiparallel π - π -stacking
⇒ hole mobilities of up to
0.18 cm² V⁻¹ s⁻¹

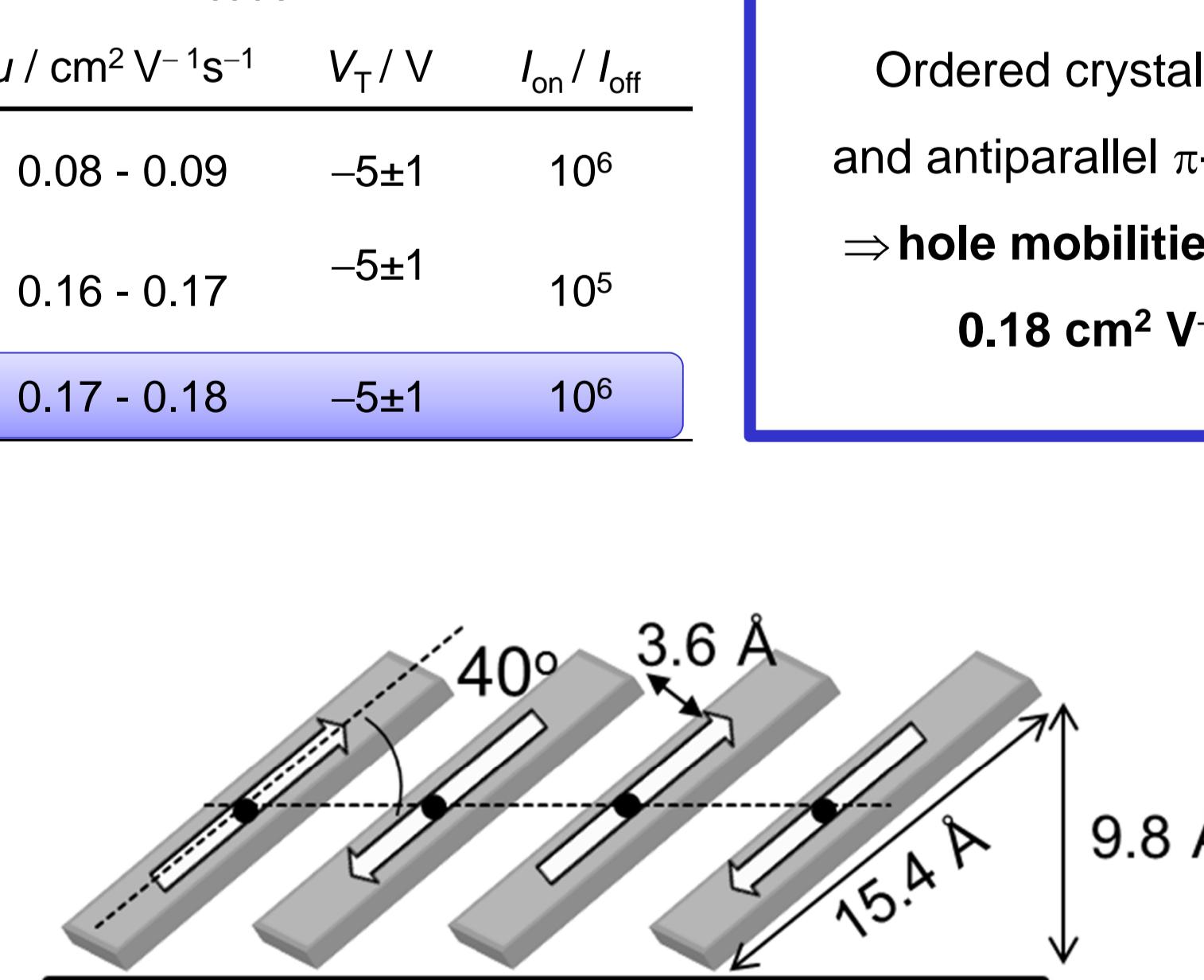


Figure 7. Packing model for thin-films of merocyanine HB255 on TPA.